## NSN 5961-00-873-3660

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-873-3660 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.645 inches **Overall Height:** 0.135 inches **Overall Width:** 0.505 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 2.50 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 65.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No